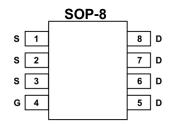
# TPC8107-HX P-Channel 30-V (D-S) MOSFET

| PRODUCT SUMMARY |                        |           |        |  |  |
|-----------------|------------------------|-----------|--------|--|--|
| VDS (V)         | RDS(on) (Ω)            | Qg (Typ.) | ID (A) |  |  |
| -30             | 0.011 at Vgs = - 10 V  | 20.5%     | -13.5  |  |  |
|                 | 0.015 at Vgs = - 4.5 V | 29.5nC    | -11.6  |  |  |





**Top View** 

### **FEATURES**

- TrenchFET<sup>®</sup> Power MOSFET
- 100 % R<sub>g</sub> Tested
- 100 % UIS Tested

### **APPLICATIONS**

- Load Switch
- Notebook Adaptor Switch

| Absolute Maximum Ratings       | (Ta = 25°C)                        |            |      |   |
|--------------------------------|------------------------------------|------------|------|---|
| Characteristics                | Symbol                             | Rating     | Unit |   |
| Drain-source voltage           | Voss                               | -30        | V    |   |
| Drain-gate voltage (Rcs = 20 k | Vdgr                               | -30        | V    |   |
| Gate-source voltage            | Gate-source voltage                |            |      | V |
|                                | DC                                 | lo         | -13  |   |
| Drain current                  | Pulse                              | lop        | -52  | A |
| Drain power dissipation (t = 1 | Drain power dissipation (t = 10 s) |            |      | W |
| Drain power dissipation (t = 1 | PD                                 | 1.0        | W    |   |
| Single pulse avalanche energ   | Eas                                | 219        | mJ   |   |
| Avalanche current              | lar                                | -13        | А    |   |
| Repetitive avalanche energy    | Ear                                | 0.19       | mJ   |   |
| Channel temperature            | Tch                                | 150        | °C   |   |
| Storage temperature range      | Tstg                               | -55 to 150 | °C   |   |

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| Characteristics                                 |               | Symbol     | Test Condition               | Min   | Тур. | Max  | Unit |
|---|---------------|------------|------------------------------|-------|------|------|------|
|   |               | +          |                              | IVIII | тур. |      |      |
| Gate leakage current                            |               | IGSS       | VGS = ±16 V, VDS = 0 V       |       |      | ±10  | μΑ   |
| Drain cut-OFF current                           |               | IDSS       | VDS = −30 V, VGS = 0 V       |       |      | -10  | μΑ   |
| Drain-source breakdown voltage                  |               | V (BR) DSS | ID = −10 mA, VGS = 0 V       | -30   |      |      |      |
|   |               | V (BR) DSX | ID = −10 mA, VGS = 20 V      | -15   |      |      | V    |
| Gate threshold voltage                          |               | Vth        | VDS = −10 V, ID = −1 mA      | -0.8  |      | -2.0 | ٧    |
| Drain-source ON resistance                      |               |            | VGS = -4 V, ID = -6.5 A      |       | 10   | 15   | mΩ   |
|   |               | RDS (ON)   | VGS = -10 V, ID = -6.5 A     |       | 5.5  | 7.0  |      |
| Forward transfer admittance                     |               | Yfs        | VDS = -10 V, ID = -6.5 A     | 15.5  | 31   |      | S    |
| Input capacitance                               |               | Ciss       | VDS = -10 V,<br>VGS = 0 V,   |       | 5880 |      | pF   |
| Reverse transfer capacitance                    |               | Crss       |                              |       | 1000 |      |      |
| Output capacitance                              |               | Coss       | f = 1 MHz                    |       | 1050 |      |      |
|   | Rise time     | tr         |                              |       | 11   |      |      |
| Switching time                                  |               |            |                              |       |      |      | ns   |
|   | Turn-ON time  | ton        |                              |       | 22   |      |      |
|   | Fall time     | tf         |                              |       | 110  |      |      |
|   | Turn-OFF time | toff       |                              |       | 395  |      |      |
| Total gate charge (gate-source plus gate-drain) |               | Qg         | V <sub>DD</sub> ~** – -24 V, |       | 130  |      |      |
| Gate-source charge 1                            |               | Qgs1       | VGS = -10 V,                 |       | 10   |      | nC   |
| Gate-drain ("miller") charge                    |               | Qgd        | ID = -13 A                   |       | 30   |      | 1    |

| Source-Drain Ratings and Characteristics (Ta = 25°C) |       |        |                        |     |      |     |      |
|--|-------|--------|------------------------|-----|------|-----|------|
| Characteristics                                      |       | Symbol | Test Condition         | Min | Тур. | Max | Unit |
| Drain reverse current                                | Pulse | IDRP   |                        |     |      | -52 | Α    |
| Forward voltage (diode)                              |       | VDSF   | IDR = -13 A, Vgs = 0 V |     |      | 1.2 | ٧    |

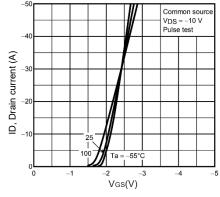


Fig 1. Gate-source voltage

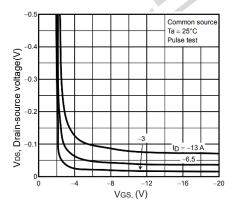


Fig 2. Gate-source voltage

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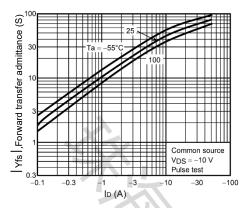


Fig 3. Drain current

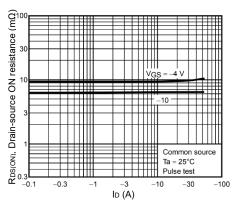


Fig 4. Drain current

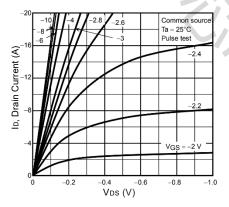


Fig 5. Drain-source voltage

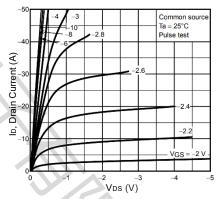


Fig 6. Drain-source voltage

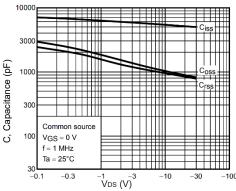


Fig 7. Drain-source voltage

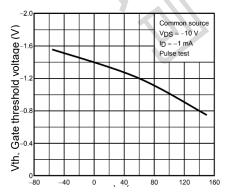


Fig 8. Ambient temperature

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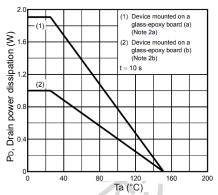


Fig 9. Ambient temperature

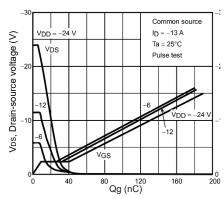


Fig 10. Total gate charge

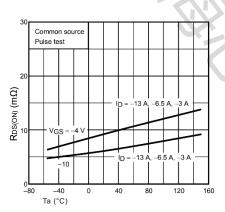


Fig 11. Ambient temperature

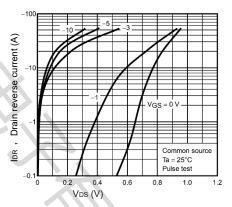


Fig 12. Drain-source voltage

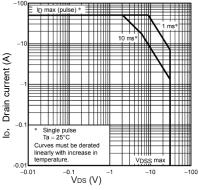


Fig 13. Drain-source voltage

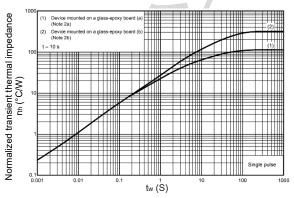
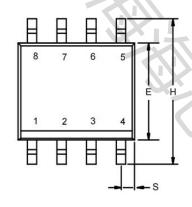


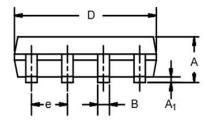
Fig 13. Pulse width

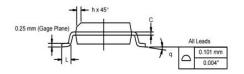
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# **SOP-8 Package Outline**

Dimensions are shown in millimeters (inches)



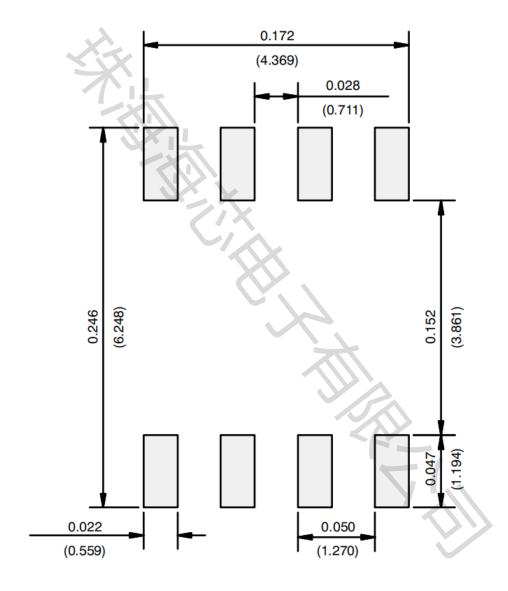




|     | MILLII | METERS  | INCHES     |       |  |
|-----|--------|---------|------------|-------|--|
| DIM | Min    | Max     | Min        | Max   |  |
| Α   | 1.35   | 1.75    | 0.053      | 0.069 |  |
| A1  | 0.10   | 0.20    | 0.004      | 0.008 |  |
| В   | 0.35   | 0.51    | 0.014      | 0.020 |  |
| С   | 0.19   | 0.25    | 0.007<br>5 | 0.010 |  |
| D   | 4.80   | 5.00    | 0.189      | 0.196 |  |
| Е   | 3.80   | 4.00    | 0.150      | 0.157 |  |
| е   | 1      | .27 BSC | 0.050 BSC  |       |  |
| Н   | 5.80   | 6.20    | 0.228      | 0.244 |  |
| h   | 0.25   | 0.50    | 0.010      | 0.020 |  |
| L   | 0.50   | 0.93    | 0.020      | 0.037 |  |
| q   | 0°     | 8°      | 0°         | 8°    |  |
| S   | 0.44   | 0.64    | 0.018      | 0.026 |  |

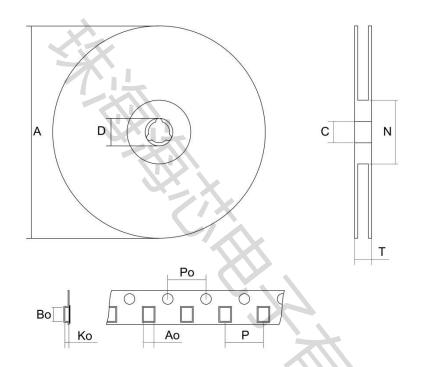
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### **RECOMMENDED MINIMUM PADS FOR SOP-8**



# **SOP-8** packing information

SOP-8 tape and reel



### **Tape orientation**

# TYPICAL User Direction of Feed

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